

Description

The 74LVCE1G08 is a single 2-input positive AND gate with a standard totem pole output. The device is designed for operation with a power supply range of 1.4V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

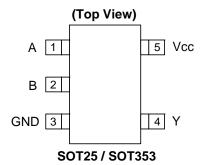
The gate performs the positive Boolean function:

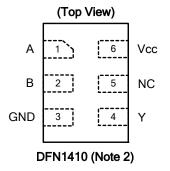
$$Y = A \bullet B$$
 or $Y = \overline{\overline{A} + \overline{B}}$

Features

- Extended Supply Voltage Range from 1.4 to 5.5V
- Switching speed characterized for operation at 1.5V
- Offers 30% speed improvement over LVC at 1.8V.
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 Exceeds 200-V Machine Model (A115-A)
 Exceeds 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- · Direct Interface with TTL Levels
- SOT25, SOT353, and DFN1410:
 Available in "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

Pin Assignments





Applications

- · Voltage Level Shifting
- General Purpose Logic
- · Wide array of products such as.
 - PCs, networking, notebooks, netbooks, PDAs
 - o Computer peripherals, hard drives, CD/DVD ROM
 - o TV, DVD, DVR, set top box
 - o Cell Phones, Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

2. Pin 2 and pin 5 of the DFN1410 package are internally connected.



Pin Descriptions

Pin Name	Description			
Α	Data Input			
В	Data Input			
GND	Ground			
Y	Data Output			
Vcc	Supply Voltage			

Logic Diagram



Function Table

Inp	Output	
Α	В	Υ
Н	Н	Н
L	Х	L
Χ	L	L



Absolute Maximum Ratings (Note 3)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
Vı	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I <0	-50	mA
I _{OK}	Output Clamp Current	-50	mA
Io	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
T _J	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Note: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 4)

Symbol		Parameter	Min	Max	Unit	
\/	On a ratio a Valta as	Operating	1.4	5.5	V	
V_{CC}	Operating Voltage	Data retention only	1.2		V	
		V _{CC} = 1.4 V to 1.95 V	0.65 X V _{CC}			
\/	IPak la al las (Maltana	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
V_{IH}	High-level Input Voltage	V _{CC} = 3 V to 3.6 V	2		V	
		V _{CC} = 4.5 V to 5.5 V	0.7 X V _{CC}			
		V _{CC} = 1.4 V to 1.95 V		0.35 X V _{CC}		
W	L our lovel input voltage	V _{CC} = 2.3 V to 2.7 V		0.7	V	
V_{IL}	Low-level input voltage	V _{CC} = 3 V to 3.6 V		0.8	V	
		V _{CC} = 4.5 V to 5.5 V		0.3 X V _{CC}		
Vı	Input Voltage		0	5.5	V	
Vo	Output Voltage		0	V _{CC}	V	
	High level output output	Vcc=1.4 V		-3		
		V _{CC} = 1.65 V		-4	m A	
		V _{CC} = 2.3 V		-8		
I _{OH}	High-level output current	V 2V		-16	mA	
		$V_{CC} = 3 \text{ V}$		-24		
		V _{CC} = 4.5 V		-32		
		Vcc=1.4 V		3		
		V _{CC} = 1.65 V		4		
		V _{CC} = 2.3 V		8	mΑ	
I _{OL}	Low-level output current			16		
		$V_{CC} = 3 V$		24		
		V _{CC} = 4.5 V		32		
		V _{CC} = 1.4 to 3V		20		
Δt/ΔV	Input transition rise or fall	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
	rate	$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		5	,	
T _A	Operating free-air temperature		-40	85	°C	

Note: 4. Unused inputs should be held at Vcc or Ground.



Electrical Characteristics (All typical values are at Vcc = 3.3V, T_A = 25°C)

Over recommended free-air temperature range (unless otherwise noted)

Symbol	Parameter	Test Conditions	Vcc	Min	Тур.	Max	Unit	
		I _{OH} = -100μA	1.4 V to 5.5V	V _{CC} - 0.1				
		$I_{OH} = -3mA$	1.4 V	1.05				
		$I_{OH} = -4mA$	1.65 V	1.2				
V_{OH}	High Level Output Voltage	$I_{OH} = -8mA$	2.3V	1.9			V	
	Voltage	I _{OH} = -16mA	3 V	2.4				
		$I_{OH} = -24mA$	3 V	2.3				
		$I_{OH} = -32mA$	4.5 V	3.8				
		$I_{OL} = 100 \mu A$	1.4 V to 5.5V			0.1		
		$I_{OL} = 3mA$	1.4 V			.4		
		I _{OL} = 4mA	1.65 V			0.45		
V_{OL}	High-level Input Voltage	$I_{OL} = 8mA$	2.3V			0.3	V	
		I _{OL} = 16mA	3 V			0.4		
		$I_{OL} = 24mA$	3 V			0.55		
		$I_{OL} = 32mA$	4.5			0.55		
l _l	Input Current	$V_1 = 5.5 \text{ V or GND}$	0 to 5.5 V			± 5	μΑ	
I _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 5.5V$	0			± 10	μΑ	
I _{CC}	Supply Current	$V_1 = 5.5V$ of GND $I_0=0$	1.4 V to 5.5V			10	μΑ	
ΔI _{CC}	Additional Supply Current	One input at V _{CC} – 0.6 V Other inputs at V _{CC} or GND	3 V to 5.5V			500	μA	
Ci	Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	3.3		3.5		pF	
	T. 15	SOT25	(Note 5)		204			
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT353	(Note 5)		371		°C/W	
	Junction-to-Ambient	DFN1410	(Note 5)		430			
		SOT25	(Note 5)		52			
θ_{JC}	Thermal Resistance	SOT353	(Note 5)		143		°C/W	
	Junction-to-Case	DFN1410	(Note 5)		190			

Note: 5. Test condition for SOT25, SOT353, and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



Switching Characteristics

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Parameter	From	то	Vcc = 1.5 V ± 0.1V				Vcc = 2.5 V ± 0.2V		Vcc = 3.3 V ± 0.3V		Vcc = 5 V ± 0.5V		Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	A or B	Y	1.5	7.2	1.0	5	0.5	3.5	0.6	2.9	0.7	2.9	ns

Over recommended free-air temperature range, CL = 30 or 50pF as noted (see Figure 2)

Parameter	From	то	Vcc = 1.5 V ± 0.1V		Vcc = 1.5 V					/cc = 3.3 V ± 0.3V		Vcc = 5 V ± 0.5V	
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t_{pd}	A or B	Y	2.4	8	1.6	5.6	0.8	4.4	0.8	3.6	0.9	3.6	ns

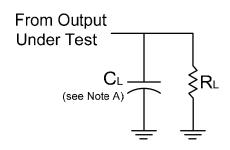
Operating Characteristics

 $T_A = 25$ °C

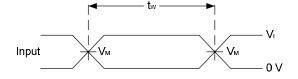
Р	arameter	Test Conditions	Vcc = 1.5 V TYP	Vcc = 1.8 V	Vcc = 2.5 V TYP	Vcc = 3.3 V	Vcc = 5 V	Unit
C _{pd}	Power dissipation capacitance	f = 10 MHz	21	21	24	26	31	pF



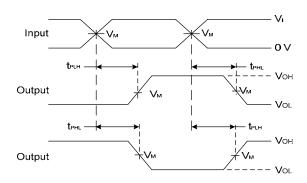
Parameter Measurement Information



Vcc	In	outs	V	6		
VCC	Vı	t _r /t _f	V _M	CL	RL	
1.5V±0.1V	V _{CC}	≤2ns	V _{CC} /2	15pF	1ΜΩ	
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	15pF	1ΜΩ	
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	15pF	1ΜΩ	
3.3V±0.3V	3V	≤2.5ns	1.5V	15pF	1ΜΩ	
5V±0.5V	V _{cc}	≤2.5ns	V _{CC} /2	15pF	1ΜΩ	



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

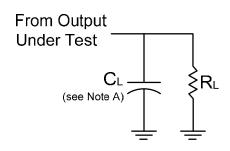
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{\text{PD.}}$

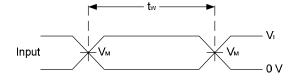
Figure 1. Load Circuit and Voltage Waveforms



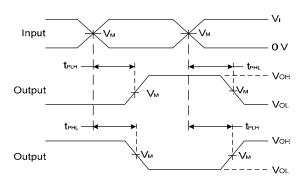
Parameter Measurement Information (Continued)



Vcc	Inp	outs	V _M	CL	RL
	Vı	t _r /t _f	- 101	96	
1.5V±0.1V	V _{CC}	≤2ns	V _{CC} /2	30pF	1ΚΩ
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	30pF	1ΚΩ
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	30pF	500Ω
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	50pF	500Ω



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.

C. Inputs are measured separately one transition per measurement.

D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$

Figure 2. Load Circuit and Voltage Waveforms



Ordering Information

T4LVCE1G 08 XXX - 7

Logic Device Function Package Packing

74: Logic Prefix 08: 2-Input W5: SOT25 7: Tape & Reel

LVCE : 1.4 to 5.5V

Family 1G : One gate AND-Gate SE:

SE: SOT353 FZ4: DFN1410

	Dovice	Device Package Packaging		7" Tape and Reel			
	Device	Code	(Note 5)	Quantity	Part Number Suffix		
P	74LVCE1G08W5-7	W6	SOT25	3000/Tape & Reel	-7		
@ ,	74LVCE1G08SE-7	SE	SOT353	3000/Tape & Reel	-7		
Pb ,	74LVCE1G08FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7		

Note: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



Marking Information

(1) SOT25 and SOT353

(Top View)

5 4

XX Y W X

2

3

1

XX : Identification code

Y: Year 0~9

<u>W</u>: Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents

52 and 53 week

X : A~Z : Internal code

Part Number	Package	Identification Code		
74LVCE1G08W5	SOT25	PV		
74LVCE1G08SE	SOT353	PU		

(2) DFN1410H4-6

(Top View)

 XX: Identification Code

Y: Year: 0~9

<u>W</u>: Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents

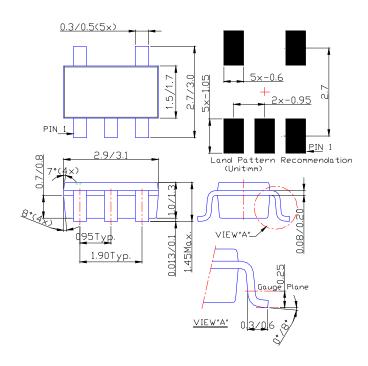
52 and 53 week \underline{X} : A~Z: Internal code

Part Number	Package	Identification Code
74LVCE1G08FZ4	DFN1410	PV

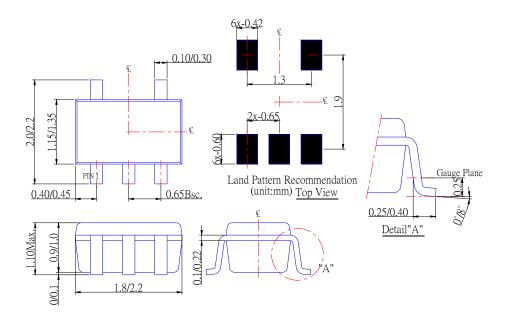


Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



(2) Package Type: SOT353

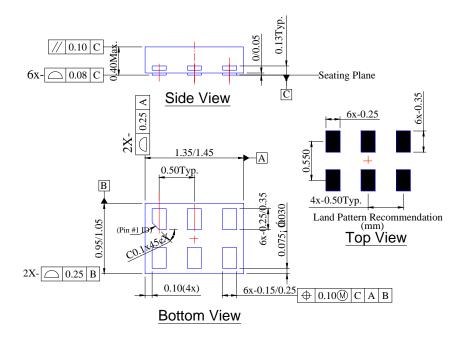


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Package Outline Dimensions (All Dimensions in mm)

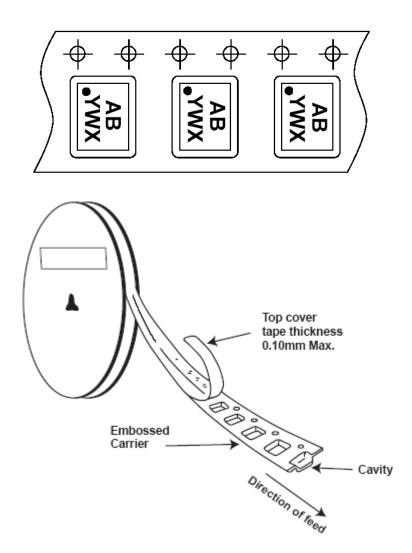
(3) Package Type: DFN1410





Taping Orientation (Note 7)

For DFN1410



Note: 7. The taping orientation of the other package type can be found on our website at http://www.diodes.com/datasheets/ap02007.pdf



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